Product Overview

The RF1126 is a single-pole double-throw (SPDT) switch designed for general purpose switching applications which require very low insertion loss and medium power handling capability. The RF1126 is ideally suited for battery operated applications requiring high performance switching with very low DC power consumption. The RF1126 features low insertion loss, high linearity, and very good harmonic characteristics, and is operable from 1.8 V to 3.6 V control voltage. It is fabricated with 0.5 μ m GaAs pHEMT process, and is packaged in a very compact 2 mm x 1.3 mm, 6-pin, leadless QFN package.

Functional Block Diagram





Package Style: QFN, 6-pin, 2 mm x 1.3 mm x 0.35 mm

Key Features

- Broadband performance low frequency to 5.8 GHz
- Very Low Insertion Loss
- 0.26 dB Typ at 1 GHz
- 0.32dB Typ at 2 GHz
- Excellent harmonics < -75 dBc at 2 GHz
- High IIP3: Cell Band Typ. 62 dBm
- 1.8 V capable for low power Applications
- P0.1 dB > 23 dBm Typ @ 2 GHz

Applications

- Cellular Handset Applications
- Antenna Tuning Applications
- IEEE802.11b/g WLAN Applications
- Multi-mode GSM, W-CDMA Applications
- WLAN Applications

Ordering Information

Part Number	Description
RF1126	Broadband Medium Power SPDT Switch
RF1126PCBA-410	Fully Assembled Evaluation Board

Absolute Maximum Ratings

Parameter	Rating	Unit
Voltage	6.0	V
Maximum input power (0.6 GHz to 2.5 GHz), RF1, RF2	+28	dBm
Operating temperature	-30 to +85	°C
Storage temperature	-65 to +100	°C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Parameter	Specification				
	Min.	Тур.	Max.	Unit	Condition
$Overall - V_{control_high} = 3 V$					V _{RF1} , V _{RF2} = High = 3 V, V _{RF1} = V _{RF2} = Low = 0 V, Temp = 25 °C
Operating Frequency	33		5800	MHz	
Insertion Loss					
		0.21	0.24	dB	RF ON, 50 MHz to 450 MHz
		0.26	0.31	dB	RF ON, 824 MHz to 960 MHz
RFC – RF1, RFC – RF2		0.32	0.40	dB	RF ON, 1850 MHz to 1990 MHz
		0.36	0.45	dB	RF ON, 2170 MHz to 2500 MHz
		0.70		dB	RF ON, 5.8 GHz
Isolation		X			
	31	33		dB	RF ON, 450 MHz
	25	27		dB	RF ON, 824 MHz to 960 MHz
RFC – RF1, RFC – RF2	18	20		dB	RF ON, 1850 MHz to 1990 MHz
	16	19		dB	RF ON, 2170 MHz to 2500 MHz
	X	11		dB	RF ON, 5.8 GHz
Return Loss	19	26		dB	500 MHz to 3000 MHz
		75		dBc	P _{IN} = +15 dBm, 1980 MHz
Second Harmonic		69		dBc	P _{IN} = +15 dBm, 2500 MHz
Third Llawsonia	X	90		dBc	P _{IN} = +15 dBm, 1980 MHz
Third Harmonic		70		dBc	P _{IN} = +15 dBm, 2500 MHz
IIP3					
RF1 – RFC, RF2 – RFC (Cell)	61	62		dBm	Tone 1: 836.5 MHz @ 16 dBm, Tone 2: 791.5 MHz @ -20 dBm Rx Freq: 881.5 MHz
RF1 – RFC, RF2 – RFC (IMT)	59	60		dBm	Tone 1: 1950 MHz @ 16 dBm, Tone 2: 1760 MHz @ -20 dBm Rx Freq: 2140 MHz
Triple Beat Ratio					
Cell/AWS/PCS		61		dBc	VSWR = 2:1
0.1 dB Compression (P0.1 dB)	21	23		dBm	500 MHz to 3000 MHz
Switching Speed		160	400	ns	50% control to 10%/90%
Control Current		0.4	1.0	μA	P _{IN} = 15 dBm

Demonstra	Specification				
Parameter	Min.	Тур.	Max.	Unit	Condition
Overall - Vcontrol_high = 1.8 V					V _{RF1} , V _{RF2} = High = 1.8 V, V _{RF1} = V _{RF2} = Low = 0 V, Temp. = 25 °C
Operating Frequency	50		5800	MHz	
Insertion Loss					
		0.21	0.30	dB	RF ON, 450 MHz
		0.26	0.35	dB	RF ON, 824 MHz to 960 MHz
RFC – RF1, RFC – RF2		0.32	0.45	dB	RF ON, 1850 MHz to 1990 MHz
		0.36	0.50	dB	RF ON, 2170 MHz to 2500 MHz
		0.70		dB	RF ON, 5.8 GHz
Isolation					
	30	32		dB	RF ON, 450 MHz
	24	25		dB	RF ON, 824 MHz to 960 MHz
RFC – RF1, RFC – RF2	17	19		dB	RF ON, 1850 MHz to 1990 MHz
	15	18		dB	RF ON, 2170 MHz to 2500 MHz
		11		dB 🐇	RF ON, 5.8 GHz
Return Loss	19	26		dB	500 MHz to 3000 MHz
0.1 dB Compression (P0.1 dB)	7	11		dBm	500 MHz to 3000 MHz
Switching Speed		160	400	ns	50% control to 10%/90%
	1.8	3.0	3.6	v	VRF1 and VRF2 (H)
DC Supply	0		0.4	v	VRF1 and VRF2 (L)
Control Current		0.4	1.0	μA	P _{IN} = 15 dBm

Control Logic

	Control Signals	Signal Paths
	VRF1 VRF2	RF1 – RFC RF2 – RFC
Valid States	1 0	ON OFF
Valid States	0 1	OFF ON
Involid States	0 0	Indeterminate State*
Invalid States	1 1	Indeterminate State*

0: Logic level low, 0 V ~ 0.4 V

1: Logic level high, 1.8 V ~ 3.6 V

Note: In indeterminate states, both signal paths are ON with degraded performance.

Pin	Function	Description
1	RF1	RF Port 1
2	GND	Ground
3	RF2	RF Port 2
4	VRF2	Control 2
5	RFC	Antenna
6	VRF1	Control 1
Pkg Base	GND	Ground

Package Drawing



Evaluation Board Schematic



Evaluation Board Layout

Board Thickness 0.067", Board Material FR-4, Multi-layer



Typical Performance Data on Evaluation Board Note: Fixture losses have been de-embedded (Temp. = 25 °C, $V_{RF1} = V_{RF2} = High = 3 V V_{RF1} = V_{RF2} = Low = 0 V$)



Solderability

Compatible with both lead-free (260 °C max. reflow temperature) and tin/lead (245 °C max. reflow temperature) soldering processes. Package lead plating: -Matte Sn

RoHS Compliance

This part is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄0₂) Free
- SVHC Free

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NOT FOR NEW DESIGNS. Contact Marketing RF1126 Broadband Medium Power SPDT Switch

REVISION HISTORY

REVISION	DESCRIPTION	
DS110405	Release version	
DS140709	Revised minimum operating frequency from 50 MHz to 33 MHz	
DS20170308	Converted from RFMD to Qorvo template	
E (20180508)	Added Not For New Design marking	

Contact Information

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